TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC4841

VHF~UHF Band Low Noise Amplifier Applications

- Low noise figure, high gain.
- NF = 1.8dB, $|S_{21e}|^2 = 8.5$ dB (f = 2 GHz)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V _{CBO}	20	V	
Collector-emitter voltage	V _{CEO}	10	V	
Emitter-base voltage	V _{EBO}	1.5	V	
Base current	Ι _Β	7	mA	
Collector current	۱ _C	15	mA	
Collector power dissipation	PC	100	mW	
Junction temperature	Тј	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	



Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f _T	$V_{CE} = 6 V, I_{C} = 7 mA$	7	10	_	GHz
nsertion gain	S _{21e} ² (1)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 7 \text{ mA}, \text{ f} = 1 \text{ GHz}$	_	13.5	_	dD
	S _{21e} ² (2)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 7 \text{ mA}, \text{ f} = 2 \text{ GHz}$	4.5	4.5 8.5 —		ub
	NF (1)	$V_{CE} = 6 \text{ V}, \text{ I}_{C} = 3 \text{ mA}, \text{ f} = 1 \text{ GHz}$		1.4		P
voise ligure	NF (2)	$V_{CE} = 6 V, I_{C} = 3 mA, f = 2 GHz$		1.8	3.0	uВ

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 10 V, I_E = 0$	_		1	μA
Emitter cut-off current	I _{EBO}	$V_{EB}=1~V,~I_C=0$			1	μA
DC current gain	h _{FE}	$V_{CE} = 6 V, I_C = 7 mA$	50	_	250	
Output capacitance	C _{ob}	$V_{00} = 10 V_{0} = 0$ f = 1 MHz (Note)	_	0.45	_	pF
Reverse transfer capacitance	C _{re}	$VCB = 10^{\circ} V, 1E = 0, 1 = 100012^{\circ}$ (1000)	_	0.35	0.8	pF

Note: Cre is measured by 3 terminal method with capacitance bridge.

Marking









S-Parameter $Z_O = 50 \Omega$, Ta = 25°C

$V_{CE}=6~V,~I_C=3~mA$

Frequency	S	11	Sź	21	Sí	12	S	22
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
200	0.823	-22.5	7.186	154.4	0.036	74.8	0.928	-14.5
400	0.685	-40.5	6.252	136.4	0.063	65.5	0.805	-23.6
600	0.537	-54.5	5.378	122.5	0.080	60.8	0.700	-28.1
800	0.428	-64.4	4.567	112.6	0.094	59.3	0.627	-30.0
1000	0.343	-71.9	3.961	104.8	0.107	59.3	0.578	-30.7
1200	0.267	-77.4	3.486	98.6	0.119	59.7	0.544	-31.1
1400	0.227	-83.4	3.104	93.3	0.131	60.2	0.518	-31.8
1600	0.187	-86.9	2.793	88.9	0.141	60.6	0.497	-32.2
1800	0.157	-90.6	2.534	85.1	0.153	62.3	0.481	-32.7
2000	0.130	-94.1	2.336	81.2	0.167	62.7	0.466	-33.2

$V_{CE} = 6 V, I_C = 7 mA$

Frequency	S	11	S2	21	Sí	2	Sź	22
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
200	0.653	-34.3	12.924	144.3	0.032	71.8	0.840	-20.9
400	0.447	-57.1	9.858	122.7	0.051	66.3	0.657	-28.3
600	0.304	-70.0	7.513	109.8	0.066	66.0	0.552	-28.9
800	0.220	-77.9	5.971	101.8	0.081	67.2	0.500	-27.9
1000	0.164	-83.4	4.955	95.6	0.096	68.5	0.470	-26.9
1200	0.123	-87.1	4.225	91.0	0.112	69.1	0.454	-26.3
1400	0.094	-93.7	3.721	86.8	0.127	69.2	0.441	-26.4
1600	0.070	-97.1	3.302	83.3	0.142	69.1	0.430	-26.8
1800	0.054	-102.8	2.974	80.2	0.156	70.1	0.423	-27.0
2000	0.039	-115.8	2.732	76.9	0.174	69.5	0.414	-27.7

30°

30°















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